

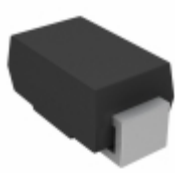
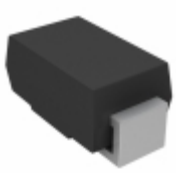
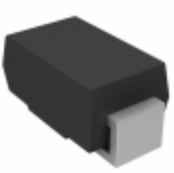

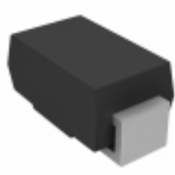

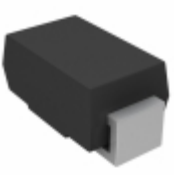
	<h2>S1MHE3_A/H</h2>
	<p><b>Hersteller-Teilenummer:</b> S1MHE3_A/H</p> <p><b>Hersteller / Marke:</b> Vishay / Semiconductor - Diodes Division</p> <p><b>Teil der Beschreibung:</b> DIODE GEN PURP 1KV 1A DO214AC</p> <p><b>Datenblätter:</b>  <a href="#">S1MHE3_A/H.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 95240 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	S1MHE3_A/H
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 1KV 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	95240 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	5µA @ 1000V
Spannung - Sperr (Vr) (max)	1000V (1kV)
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

S1MHE3\_A/H ist neu im Original, Suche S1MHE3\_A/H Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1MHE3\_A/H Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S1MHE3\_A/H: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>S1MG</b> Original S1MG Original</p>	 <p><b>S1MHE3_A/I</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MHE3/61T</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 1KV 1A DO214AC</p>
 <p><b>S1MMH2G</b> TSC (Taiwan Semiconductor) DIODE GEN PURP 1000V 1A DO214AC</p>	 <p><b>S1MHE3/5AT</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MHR3G</b> TSC (Taiwan Semiconductor) DIODE GEN PURP 1000V 1A DO214AC</p>	 <p><b>S1MHE3_A/H</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 1KV 1A DO214AC</p>

### heiße Teile

Mehr

08051A0R5BAT2A	1812CC471KAT3A\SB	ADP7118AUJZ-3.3-R7	AM50P06-15D	AP18N20GP-HF
BTB08-800C	CDRH2D11-1R5NC	CL05C221JA5NNNC	FSD268TA	GRM0336S1E7R3DD01D
GRM31MR72H102KY21L	ICS9P750CG	IMP1117AD5X1T	ISL6255HRZ-TR	KP1000A2200V
KV1735ASTL-G	LM-231-09	NJM2828F3-15-TE1	NJU7221U15-TE1	S1M-13-F
S1M-E3/5AT	S1M-E3/5AT	S1M-E3/61T	S1M-E3/61T	S1M-M3/61T
S1M-M3/61T	S1M0V043B1J8100	S1M8656A01-F0T0	S1M8662A01-Z070	S1M8691X01-J070
S1M8732X01-Y070	S1M8837X01	S1M8837X01-N0T0	S1MB-13-F	S1MHE3/61T
S1MHE3/61T	S1MHE3_A/H	S1MHE3_A/I	S1MHE3_A/I	S1MSP1-F
S1MSWF-7	S1MSWFQ-7	S29JL064H70TFI00	SI5933DC-T3	SMBJ48CA-CT7
STTH16L06CG-TR	TDA8034T/C1	THS4042IDR	TISP5115H3BJR-S	V48B2C100BN3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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